

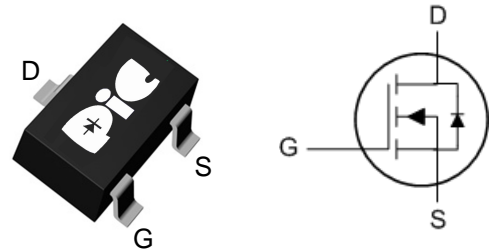
➤ General Description

This PAN1526SN N-Channel enhancement mode power field effect transistor is the high density trench technology and this advanced technology can provide excellent $R_{ds(On)}$ performance and efficiency for power switching and load switching application., this device also comply with the RoHS and Green Product requirement with full function reliability approved.

➤ Feature

- Super high density cell design for extremely low $R_{DS(ON)}$
- Exceptional on-resistance and maximum DC current capability
- SOT-23 package design

➤ SOT-23



➤ Application

- DC/DC Converters
- Load Switch
- LED Backlighting in LCD TVs

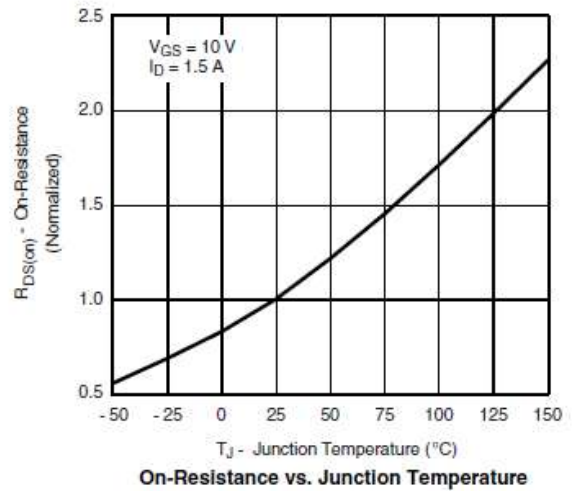
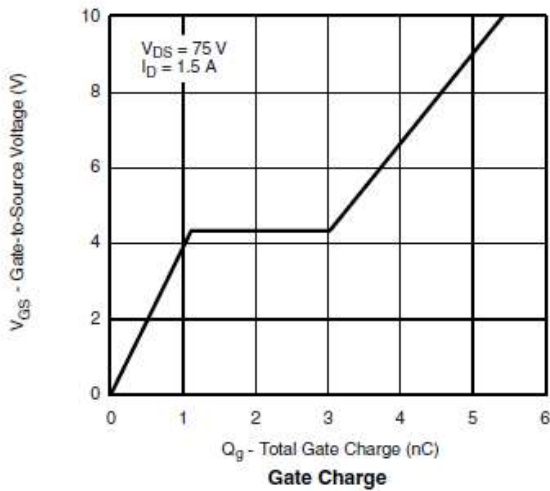
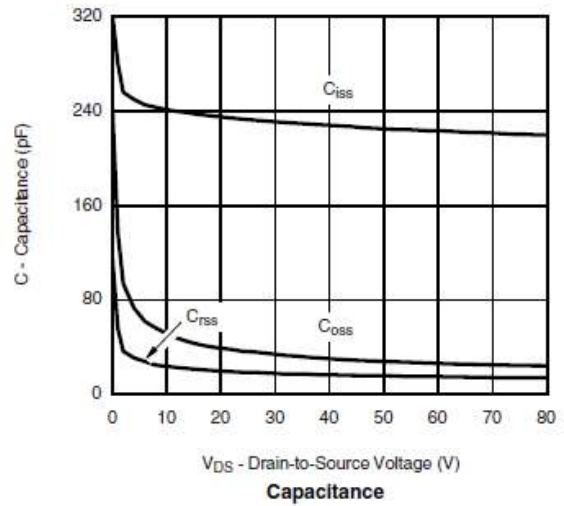
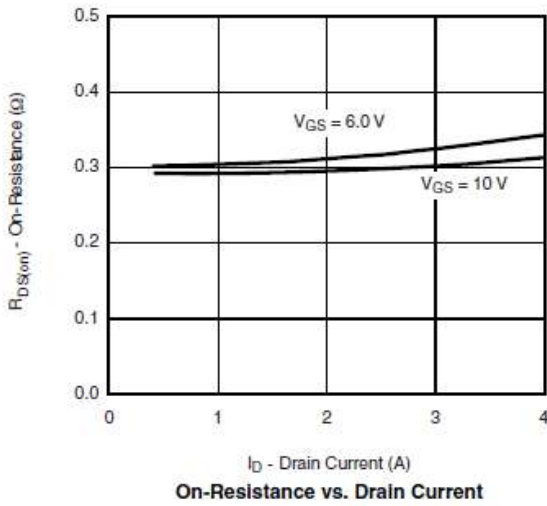
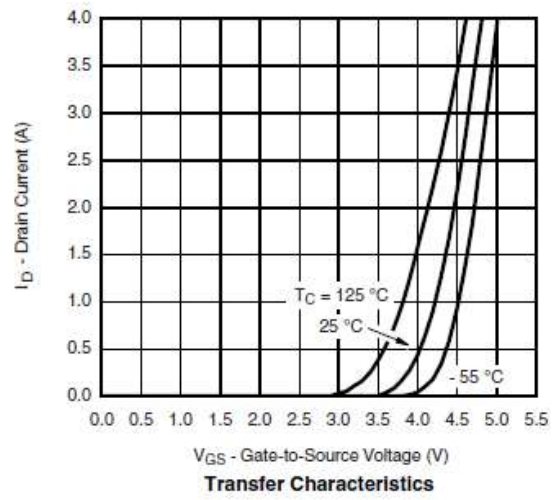
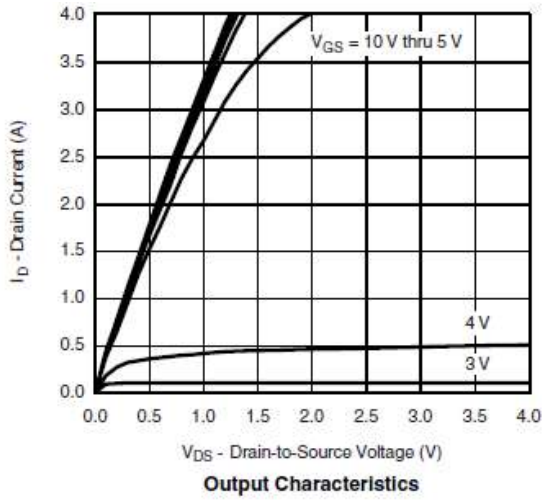
➤ Absolute Maximum Ratings

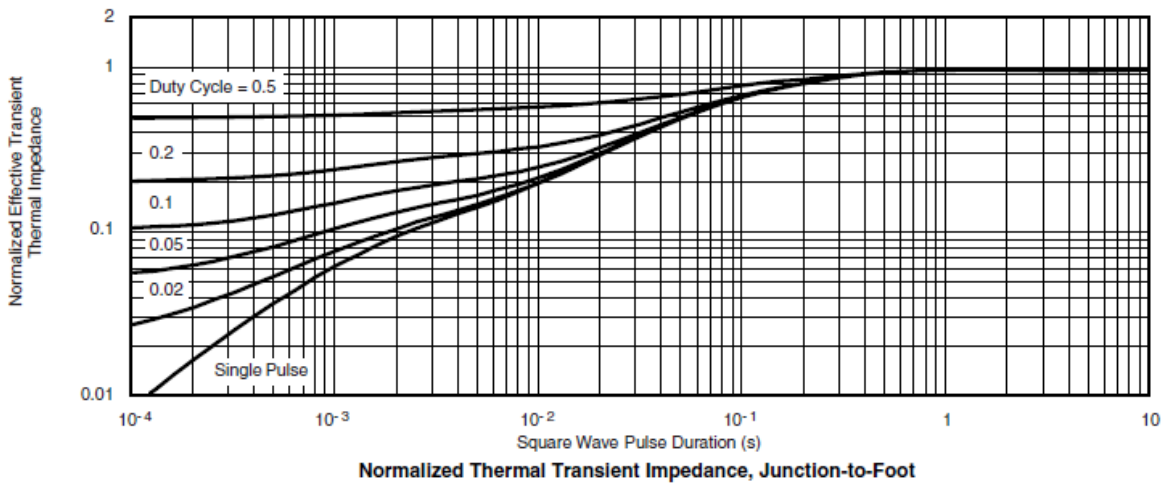
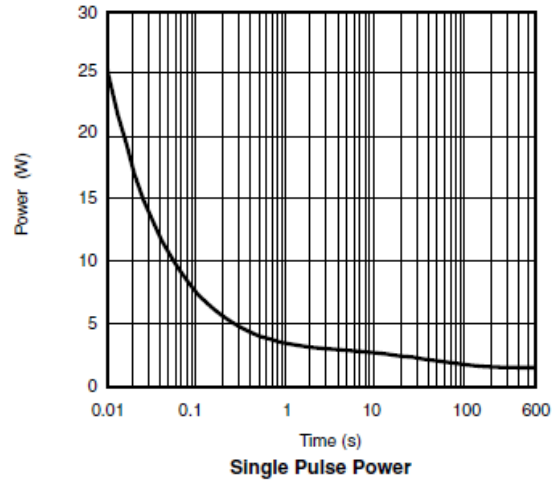
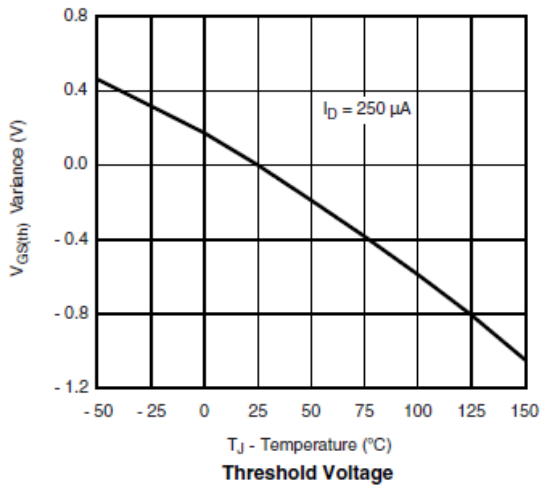
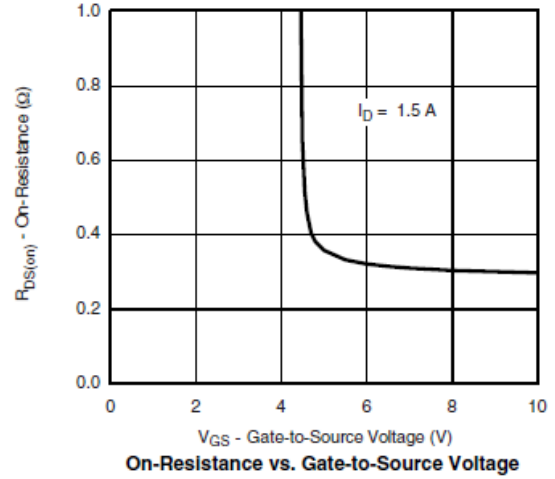
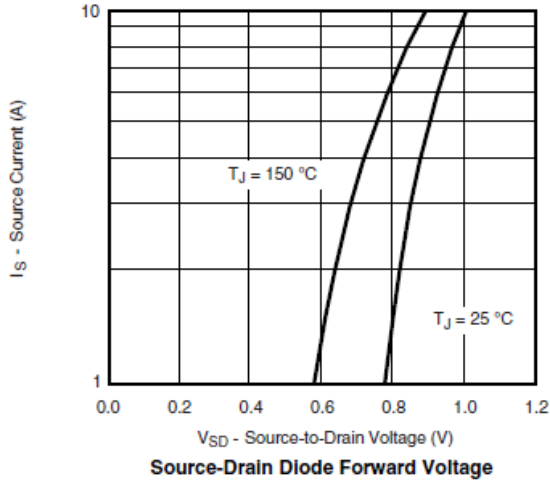
Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DSS}	150	V
Gate –Source Voltage	V_{GSS}	± 20	V
Continuous Drain Current($T_J=150^\circ C$)	I_D	$T_C=25^\circ C$	1.5
		$T_C=70^\circ C$	1.1
Pulsed Drain Current	I_{DM}	6	A
Continuous Source Current(Diode Conduction)	I_S	4	A
Power Dissipation	P_D	$T_A=25^\circ C$	2.0
		$T_A=70^\circ C$	1.3
Operating Junction Temperature	T_J	150	$^\circ C$
Storage Temperature Range	T_{STG}	-55/150	$^\circ C$
Thermal Resistance-Junction to Ambient	$R_{\theta JA}$	120	$^\circ C/W$

➤ **Electrical Characteristics ($T_A=25^\circ C$ Unless otherwise noted)**

Parameter	Symbol	Conditions	Min.	Typ	Max.	Unit
Static						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	150			V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1.0		3.0	
Gate Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 20V$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=120V, V_{GS}=0V$			1	uA
		$V_{DS}=100V, V_{GS}=0V$ $T_J=85^\circ C$			10	
On-State Drain Current	$I_{D(on)}$	$V_{DS} \geq 5V, V_{GS}=4.5V$	5			A
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=1.5A$		245	320	mΩ
		$V_{GS}=6V, I_D=1.4A$		265	340	
Forward Transconductance	g_{FS}	$V_{DS}=15V, I_D=1.5A$		4.1		S
Diode Forward Voltage	V_{SD}	$I_S=1.7A, V_{GS}=0V$		0.85	1.2	V
Dynamic						
Total Gate Charge	Q_g	$V_{DS}=75V, V_{GS}=10V$ $I_D \equiv 1.5A$		5.5	10	nC
Gate-Source Charge	Q_{gs}			1.2		
Gate-Drain Charge	Q_{gd}			2.0		
Input Capacitance	C_{iss}	$V_{DS}=50V, V_{GS}=0V$ $f=1MHz$		400		pF
Output Capacitance	C_{oss}			20		
Reverse Transfer Capacitance	C_{riss}			15		
Turn-On Time	$t_{d(on)}$	$V_{DD}=75V, R_L=75\Omega$ $I_D \equiv 1.0A, V_{GEN}=10V$ $R_G=6\Omega$		10	20	ns
	t_r			10	20	
Turn-Off Time	$t_{d(off)}$			25	50	
	t_f			15	30	

➤ Typical Characteristics





➤ Recommend IR Reflow Soldering Thermal Profile

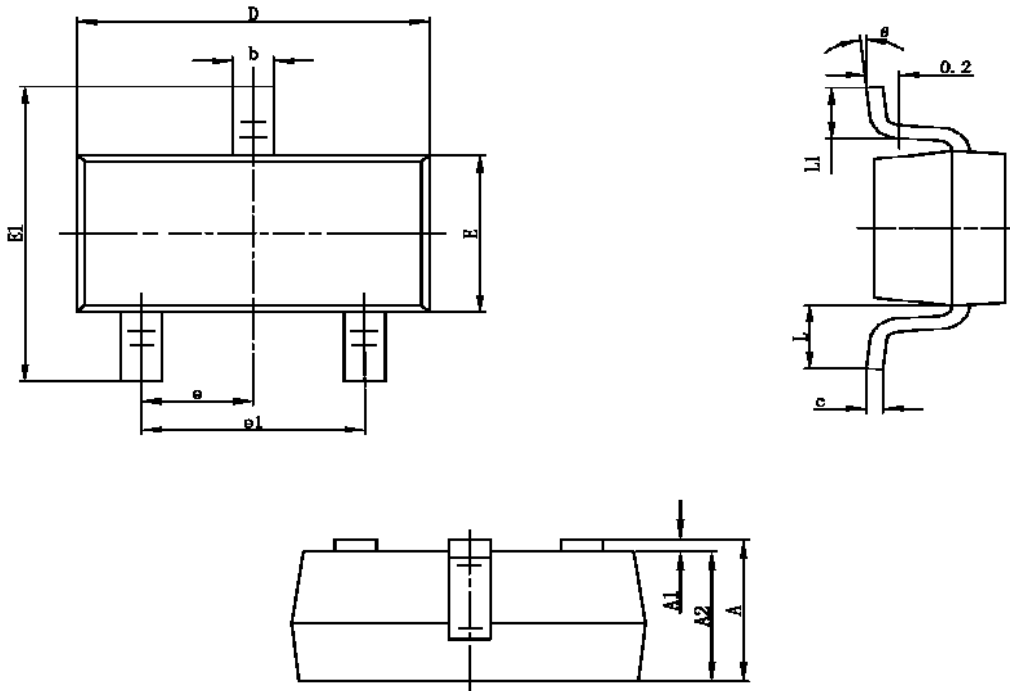


Profile Feature	Pb-Free Assembly Profile
Temperature Min. (T Amin)	150°C
Temperature Max. (Tsmax)	200°C
Time (ts) from (T Amin to Tsmax)	60-120 seconds
Average Ramp-up Rate (tL to tP)	3°C/second max.
Liquidous Temperature (TL)	217°C
Time (tL) Maintained Above (TL)	60 – 150 seconds
Peak Temperature	260°C +0°C / -5°C
Time (tP) within 5°C of actual Peak Temperature	30 seconds
Ramp-down Rate (TP to TL)	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.

➤ Ordering Information

Part Number	Description	Quantity
PAN1526SN	SOT-23 Reel	3000 pcs

➤ Package Information (SOT-23)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.400	0.012	0.016
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.700REF		0.028REF	
L1	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

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